

-30V Dual P-Channel Enhancement Mode MOSFET

■ DESCRIPTION

The SMC4923 is the Dual P-Channel logic enhancement mode power field effect transistor is produced using high cell density advanced trench technology to provide excellent $R_{DS(ON)}$.

This device is suitable for use as a load switch or in PWM and gate charge for most of the synchronous buck converter applications.

SMC4923M-TRG RoHS Compliant This is Halogen Free

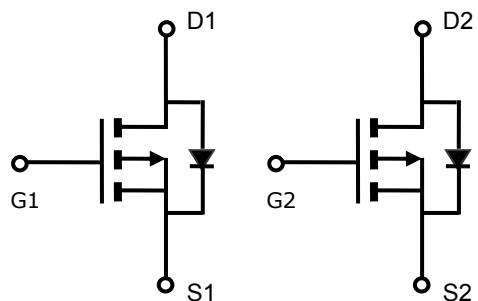
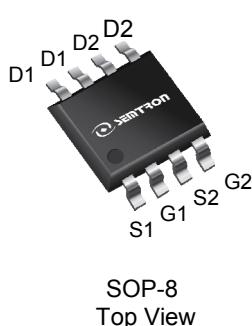
■ FEATURE

- ◆ -30V/-9.0A, $R_{DS(ON)} = 10m\Omega(typ)$ @ $V_{GS} = -20V$
- ◆ -30V/-8.0A, $R_{DS(ON)} = 12m\Omega(typ)$ @ $V_{GS} = -10V$
- ◆ -30V/-5.0A, $R_{DS(ON)} = 16m\Omega(typ)$ @ $V_{GS} = -4.5V$
- ◆ Super high density cell design for extremely low $R_{DS(ON)}$
- ◆ Exceptional on-resistance and maximum DC current capability
- ◆ SOP-8 package design

■ APPLICATIONS

- ◆ High Frequency Point-of-Load Synchronous
- ◆ Networking DC-DC Power System
- ◆ Load Switch

■ PIN CONFIGURATION



SMC 4923 M - TR G

a : Company name.
 b : Product Serial number.
 c : Package code
 d : Handling code
 e : Green produce code

■ ORDERING INFORMATION

Part Number	Package Code	Handling Code	Shipping
SMC4923M-TRG	M : SOP-8	TR : Tape&Reel	2.5K/Reel

※ Year Code : 0 ~ 9, 2010 : 0

※ Week Code : A(1~2) ~ Z(53~54)

※ SOP-8 : Only available in tape and reel packaging.

■ ABSOLUTE MAXIMUM RATINGS (TA = 25°C Unless otherwise noted)

Symbol	Parameter		Typical	Unit
V _{DSS}	Drain-Source Voltage		-30	V
V _{GSS}	Gate-Source Voltage		±25	V
I _D	Continuous Drain Current (T _c =25°C) ^A		-9	A
	Continuous Drain Current (T _c =70°C)		-7	A
I _{DM}	Pulsed Drain Current ^B		-40	A
E _{AS}	Single Pulse Avalanche energy L=0.1mH ^C		50	mJ
P _D	Power Dissipation	T _A =25°C T _A =70°C	2.0 1.4	W
T _J	Operation Junction Temperature		-55 to150	°C
T _{STG}	Storage Temperature Range		-55 to150	°C

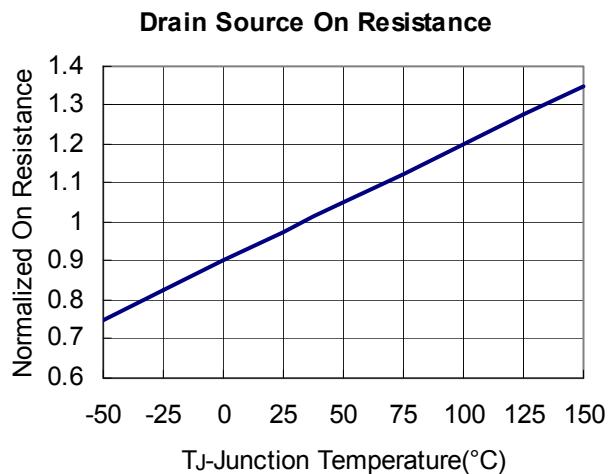
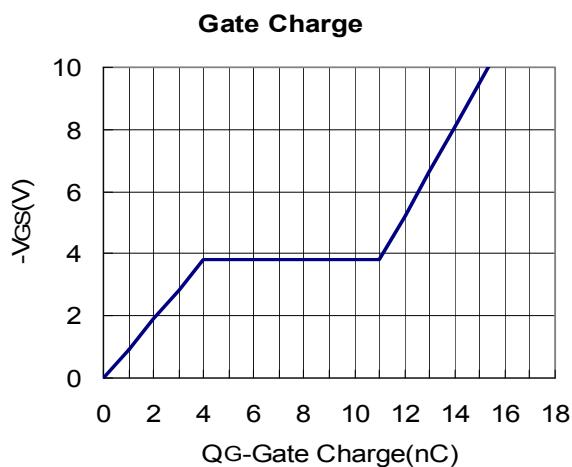
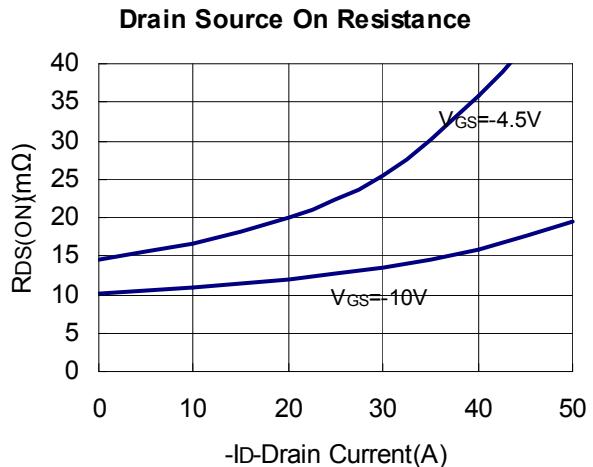
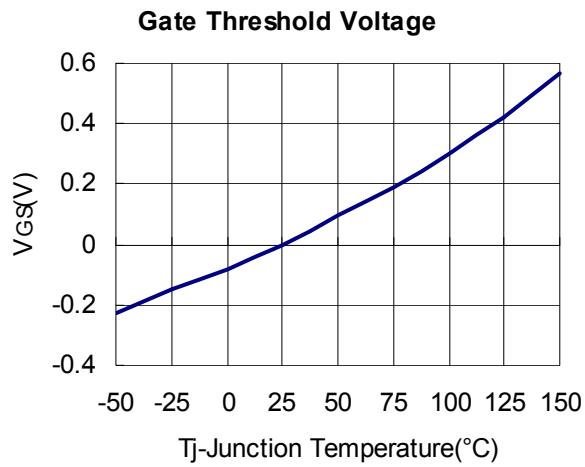
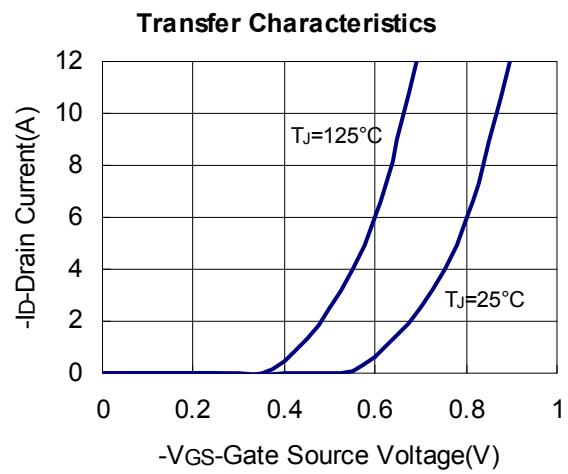
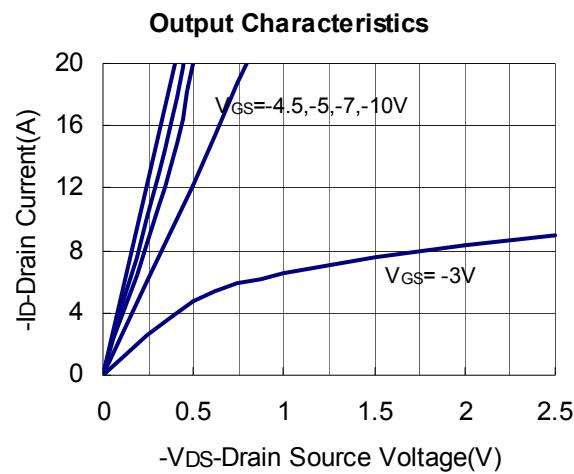
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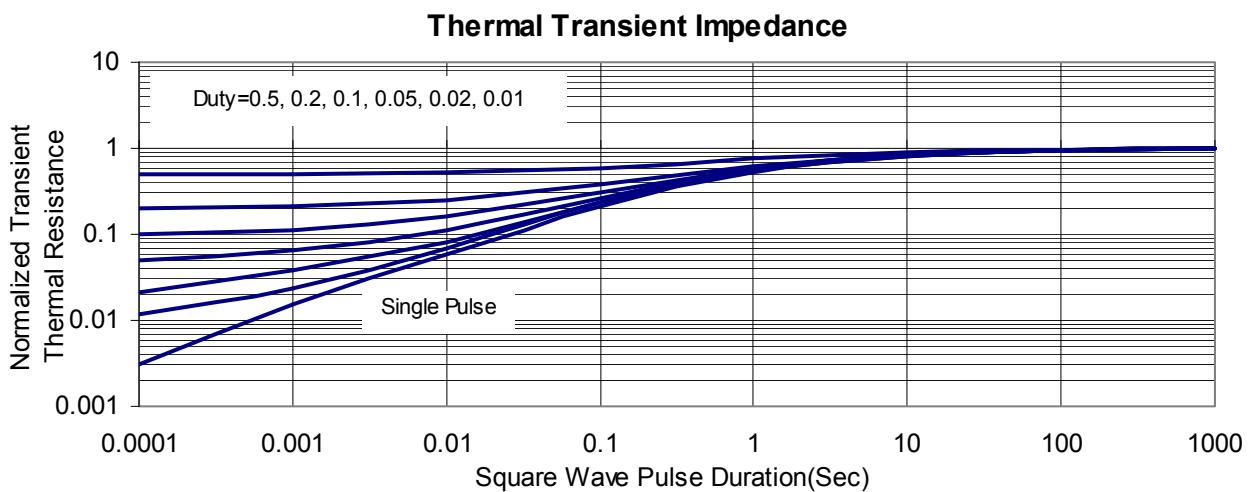
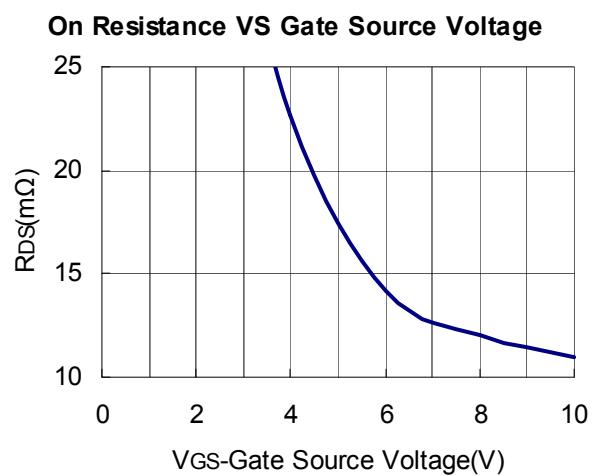
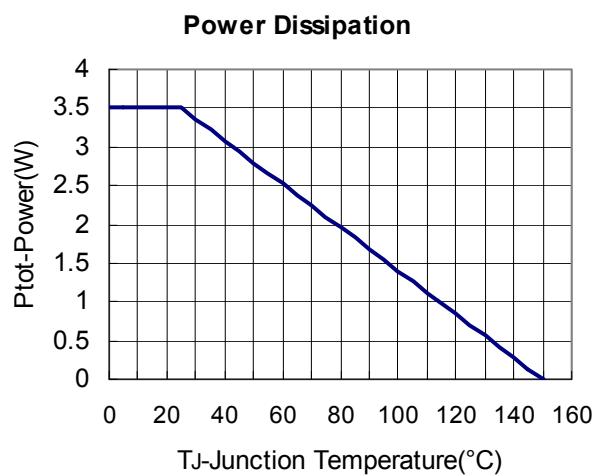
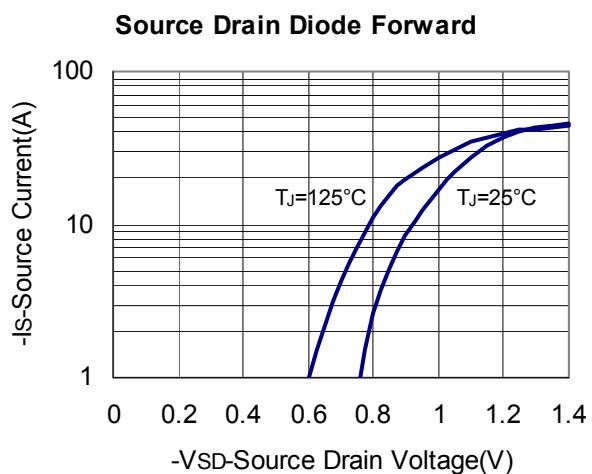
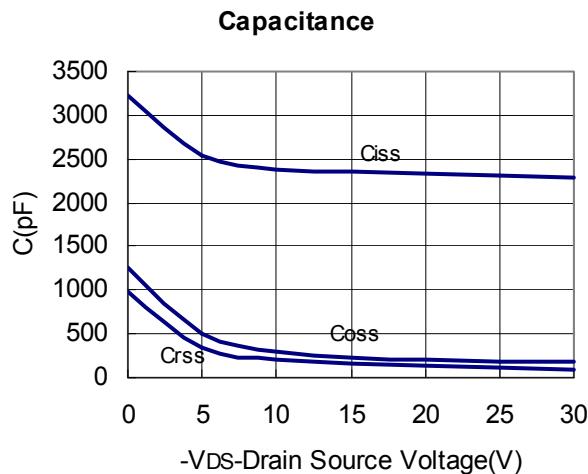
A.The value of R_{θJA} is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.B.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%

Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

Symbol	Parameter	Typ	Max	Unit
R _{θJA}	Thermal Resistance-Junction to Ambient ^A Steady-State	-	65	°C/W
R _{θJL}	Thermal Resistance Junction to Lead ^A Steady-State	-	45	°C/W

TYPICAL CHARACTERISTICS (25°C Unless Note)


TYPICAL CHARACTERISTICS (25°C Unless Note)


SOP-8 PACKAGE DIMENSIONS

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.040	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

